

# TPS22991 5V, 3A, 25mΩ Load Switch Device With Small Plastic Package

## 1 Features

- Integrated single channel load switch
  - Input voltage range: 1V to 5.5V
  - 3A maximum continuous switch current
  - 25mΩ typical ON-resistance
  - Low quiescent current:
    - $I_Q$  at 3.3V  $V_{IN} = 6\mu A$  (typ)
  - Low shutdown current:
    - $I_{SD}$  at 3.3V  $V_{IN} = 14nA$  (typ)
  - Controlled slew rate:
    - Version B, BN: rise time ( $t_R$ ) at 3.3V  $V_{IN} = 141\mu s$
    - Version C, CN: rise time ( $t_R$ ) at 3.3V  $V_{IN} = 845\mu s$
  - Quick output discharge (QOD) of 150Ω
  - Thermal shutdown protection
  - 0.85 × 0.75mm, 0.4mm pitch UQFN<sup>(1)</sup> package
1. For the pre-production units, package will be in WQFN package. WQFN package has the same footprint as UQFN package, but the height will be 0.75mm compared to 0.6mm with UQFN package. The final production units will be in UQFN package. Please contact TI for additional information.

## 2 Applications

- [PC and notebooks](#)
- [Wearables](#)
- [Solid state drive \(SSD\)](#)
- [Industrial PC](#)

## 3 Description

The TPS22991 is a small, low  $R_{ON}$ , single channel load switch with controlled slew rate. The device contains an N-channel MOSFET that can operate over an input voltage range of 1.0V to 5.5V and can support a maximum continuous current of 3A. The switch is controlled by an on and off input, which is capable of interfacing directly with low-voltage control signals.

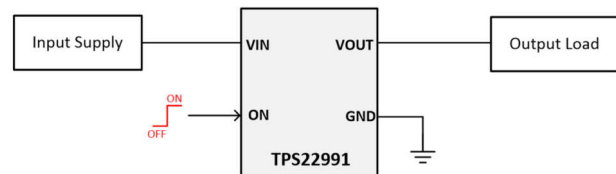
The small size and low  $R_{ON}$  makes the device ideal for being used in space constrained, battery powered applications. The wide input voltage range of the switch makes it a versatile solution for many different voltage rails. The controlled rise time of the device greatly reduces inrush current caused by large bulk load capacitances, thereby reducing or eliminating power supply droop. The TPS22991 further reduces the total solution size by integrating a 150Ω pulldown resistor for quick output discharge (QOD) when the switch is turned off.

The TPS22991 is available in a small, space saving 0.85mm × 0.75mm, 0.4mm pitch, 4-pin UQFN package. The device is characterized for operation over the free-air temperature range of  $-55^{\circ}C$  to  $+125^{\circ}C$ .

### Package Information

PART NUMBER	PACKAGE <sup>(1)</sup>	PACKAGE SIZE <sup>(2)</sup>
TPS22991	RAA (UQFN, 4)	0.85mm × 0.75mm

- (1) For all available packages, see the orderable addendum at the end of the data sheet.
- (2) The package size (length × width) is a nominal value and includes pins, where applicable.



**TPS22991 Typical Application**



## Table of Contents

<b>1 Features</b> .....	1	9.2 Functional Block Diagram.....	12
<b>2 Applications</b> .....	1	9.3 Feature Description.....	12
<b>3 Description</b> .....	1	9.4 Device Functional Modes.....	13
<b>4 Device Comparison Table</b> .....	3	<b>10 Application and Implementation</b> .....	14
<b>5 Pin Configuration and Functions</b> .....	4	10.1 Application Information.....	14
<b>6 Specifications</b> .....	5	10.2 Typical Application.....	14
6.1 Absolute Maximum Ratings.....	5	10.3 Power Supply Recommendations.....	15
6.2 ESD Ratings.....	5	10.4 Layout.....	16
6.3 Recommended Operating Conditions.....	5	<b>11 Device and Documentation Support</b> .....	17
6.4 Thermal Information.....	5	11.1 Receiving Notification of Documentation Updates..	17
6.5 Electrical Characteristics.....	6	11.2 Support Resources.....	17
6.6 Switching Characteristics (Version C, CN).....	7	11.3 Trademarks.....	17
6.7 Switching Characteristics (Version B, BN).....	7	11.4 Electrostatic Discharge Caution.....	17
<b>7 Typical Characteristics</b> .....	9	11.5 Glossary.....	17
<b>8 Parameter Measurement Information</b> .....	11	<b>12 Revision History</b> .....	17
<b>9 Detailed Description</b> .....	12	<b>13 Mechanical, Packaging, and Orderable Information</b> .....	18
9.1 Overview.....	12		

## 4 Device Comparison Table

**Table 4-1. Functionality Comparison**

PART NUMBER	QUICK OUTPUT DISCHARGE (QOD)	TURN ON TIME
TPS22991B	Yes	Fast
TPS22991BN <sup>(1)</sup>	No	Fast
TPS22991C <sup>(1)</sup>	Yes	Slow
TPS22991CN <sup>(1)</sup>	No	Slow

(1) Device in preview. Please contact TI for more information.

## 5 Pin Configuration and Functions



Figure 5-1. TPS22991 RAA Package, 4-Pin UQFN (Top View)

Table 5-1. Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		
VIN	1	I	Switch input.
ON	2	I	Active high switch control input.
VOUT	3	O	Switch output.
GND	4	—	Device ground.

## 6 Specifications

### 6.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
V <sub>IN</sub>	Maximum input voltage range	-0.3	6	V
V <sub>OUT</sub>	Maximum output voltage range	-0.3	6	V
V <sub>ON</sub>	Maximum ON pin voltage range	-0.3	6	V
I <sub>MAX</sub>	Maximum continuous current		3	A
I <sub>PLS</sub>	Maximum pulsed current (2ms, 2% duty cycle)		4	A
T <sub>J</sub>	Junction temperature	-55	150	°C
T <sub>STG</sub>	Storage temperature	-65	150	°C
T <sub>LEAD</sub>	Maximum lead temperature (10s soldering time)		300	°C

- (1) Stresses beyond those listed under *Absolute Maximum Rating* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Condition*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### 6.2 ESD Ratings

		VALUE	UNIT
V <sub>(ESD)</sub>	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/ JEDEC JS-001, all pins <sup>(1)</sup>	±2000
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins <sup>(2)</sup>	±1000

- (1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.  
(2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process. Manufacturing with less is possible with the necessary precautions. Pins listed may actually have higher performance.

### 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	TYP	MAX	UNIT
V <sub>IN</sub>	Input voltage range	1.0		5.5	V
V <sub>OUT</sub>	Output voltage range	0		5.5	V
V <sub>IH</sub>	ON pin high voltage Range	0.8		5.5	V
V <sub>IL</sub>	ON pin low voltage range	0		0.35	V
T <sub>A</sub>	Ambient temperature	-55		125	°C

### 6.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>		TPS22991	UNIT
		4 PINS	
		RAA	
R <sub>θJA</sub>	Junction-to-ambient thermal resistance	225.3	°C/W
R <sub>θJC(top)</sub>	Junction-to-case (top) thermal resistance	214.5	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	83.6	°C/W
Ψ <sub>JT</sub>	Junction-to-top characterization parameter	13.1	°C/W
Ψ <sub>JB</sub>	Junction-to-board characterization parameter	83	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## 6.5 Electrical Characteristics

Typical values at VIN = 3.3V unless otherwise specified

PARAMETER		TEST CONDITIONS		T <sub>A</sub>	MIN	TYP	MAX	UNIT		
<b>INPUT SUPPLY (VIN)</b>										
I <sub>Q, VIN</sub>	VIN quiescent current	V <sub>ON</sub> ≥ V <sub>IH</sub> , V <sub>OUT</sub> = Open		25°C		6		μA		
				-40°C to 85°C			12		μA	
				-55°C to 125°C			14		μA	
I <sub>SD, VIN</sub>	VIN shutdown current	V <sub>ON</sub> ≤ V <sub>IL</sub> , V <sub>OUT</sub> = Open		25°C		14		nA		
				-40°C to 85°C			9		μA	
				-55°C to 125°C			61		μA	
I <sub>SD, VIN</sub>	VIN shutdown current	V <sub>ON</sub> ≤ V <sub>IL</sub> , V <sub>OUT</sub> = GND	V <sub>ON</sub> ≤ V <sub>IL</sub> , V <sub>OUT</sub> = GND	25°C		15		nA		
				-40°C to 85°C			9		μA	
				-55°C to 125°C			41		μA	
<b>ON-RESISTANCE (RON)</b>										
R <sub>ON</sub>	ON-state resistance	I <sub>OUT</sub> = -200mA		V <sub>IN</sub> = 5V	25°C		25		mΩ	
					-40°C to 85°C			35		mΩ
					-40°C to 105°C			38		mΩ
					-55°C to 125°C			40		mΩ
				V <sub>IN</sub> = 3.3V	25°C		25		mΩ	
					-40°C to 85°C			35		mΩ
					-40°C to 105°C			38		mΩ
					-55°C to 125°C			40		mΩ
				V <sub>IN</sub> = 1.8V	25°C		25		mΩ	
					-40°C to 85°C			35		mΩ
					-40°C to 105°C			38		mΩ
					-55°C to 125°C			40		mΩ
				V <sub>IN</sub> = 1V	25°C		35		mΩ	
					-40°C to 85°C			48		mΩ
					-40°C to 105°C			52		mΩ
					-55°C to 125°C			60		mΩ
<b>THERMAL SHUTDOWN (TSD)</b>										
T <sub>SD,R</sub>	Thermal shutdown			Rising		170		°C		
T <sub>SD,F</sub>	Thermal shutdown			Falling		150		°C		
<b>ENABLE PIN (ON)</b>										
I <sub>ON</sub>	ON pin leakage	V <sub>ON</sub> ≥ V <sub>IH</sub>		-55°C to 125°C		100		nA		
R <sub>PD, ON</sub>	Smart pull down resistance	V <sub>ON</sub> ≤ V <sub>IL</sub>		-55°C to 125°C		500		kΩ		
V <sub>IH, ON</sub>	ON pin threshold (VIH rising)			-55°C to 125°C		0.8		V		
V <sub>Hys, ON</sub>	ON pin threshold (hysteresis)			-55°C to 125°C		0.06 5		V		
V <sub>IL, ON</sub>	ON pin threshold (VIL falling)			-55°C to 125°C		0.35		V		
<b>QUICK OUTPUT DISCHARGE (QOD)</b>										
R <sub>QOD</sub>	QOD pin internal discharge resistance (Version B, C)	V <sub>ON</sub> ≤ V <sub>IL</sub>		V <sub>IN</sub> = 1V	-55°C to 125°C		190		Ω	
				V <sub>IN</sub> = 3.3V	-55°C to 125°C		150		Ω	
				V <sub>IN</sub> = 5V	-55°C to 125°C		140		Ω	

## 6.6 Switching Characteristics (Version C, CN)

Unless otherwise noted, the typical characteristics in the following table apply to an input voltage of 3.3V, an ambient temperature of 25°C, and a load of CL = 0.1µF, RL = 10Ω. Timing parameter measurement details are shown in the timing diagram in the data sheet.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t <sub>ON</sub>	Turn ON time	V <sub>IN</sub> = 5.0V		1431		µs
		V <sub>IN</sub> = 3.3V		1300		µs
		V <sub>IN</sub> = 1.8V		1110		µs
		V <sub>IN</sub> = 1.0V		1000		µs
t <sub>R</sub>	Output rise time	V <sub>IN</sub> = 5.0V		1000		µs
		V <sub>IN</sub> = 3.3V		845		µs
		V <sub>IN</sub> = 1.8V		639		µs
		V <sub>IN</sub> = 1.0V		493		µs
t <sub>D</sub>	Delay time	V <sub>IN</sub> = 5.0V		432		µs
		V <sub>IN</sub> = 3.3V		455		µs
		V <sub>IN</sub> = 1.8V		471		µs
		V <sub>IN</sub> = 1.0V		510		µs
t <sub>OFF</sub>	Turn OFF time	V <sub>IN</sub> = 5.0V		7.5		µs
		V <sub>IN</sub> = 3.3V		5		µs
		V <sub>IN</sub> = 1.8V		3		µs
		V <sub>IN</sub> = 1.0V		5		µs
t <sub>F</sub>	Output Fall time	V <sub>IN</sub> = 5.0V		2		µs
		V <sub>IN</sub> = 3.3V		2		µs
		V <sub>IN</sub> = 1.8V		2		µs
		V <sub>IN</sub> = 1.0V		2.7		µs

## 6.7 Switching Characteristics (Version B, BN)

Unless otherwise noted, the typical characteristics in the following table apply to an input voltage of 3.3V, an ambient temperature of 25°C, and a load of CL = 0.1µF, RL = 10Ω. Timing parameter measurement details are shown in the timing diagram in the data sheet.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t <sub>ON</sub>	Turn ON time	V <sub>IN</sub> = 5.0V		302		µs
		V <sub>IN</sub> = 3.3V		259		µs
		V <sub>IN</sub> = 1.8V		216		µs
		V <sub>IN</sub> = 1.0V		198		µs
t <sub>R</sub>	Output rise time	V <sub>IN</sub> = 5.0V		173		µs
		V <sub>IN</sub> = 3.3V		141		µs
		V <sub>IN</sub> = 1.8V		107		µs
		V <sub>IN</sub> = 1.0V		81		µs
t <sub>D</sub>	Delay time	V <sub>IN</sub> = 5.0V		127		µs
		V <sub>IN</sub> = 3.3V		117		µs
		V <sub>IN</sub> = 1.8V		109		µs
		V <sub>IN</sub> = 1.0V		116		µs
t <sub>OFF</sub>	Turn OFF time	V <sub>IN</sub> = 5.0V		7.5		µs
		V <sub>IN</sub> = 3.3V		5		µs
		V <sub>IN</sub> = 1.8V		3		µs
		V <sub>IN</sub> = 1.0V		5		µs

## 6.7 Switching Characteristics (Version B, BN) (continued)

Unless otherwise noted, the typical characteristics in the following table apply to an input voltage of 3.3V, an ambient temperature of 25°C, and a load of  $CL = 0.1\mu F$ ,  $RL = 10\Omega$ . Timing parameter measurement details are shown in the timing diagram in the data sheet.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_F$	Output fall time	VIN = 5.0V		2		$\mu s$
		VIN = 3.3V		2		$\mu s$
		VIN = 1.8V		2		$\mu s$
		VIN = 1.0V		2.7		$\mu s$



## 7 Typical Characteristics

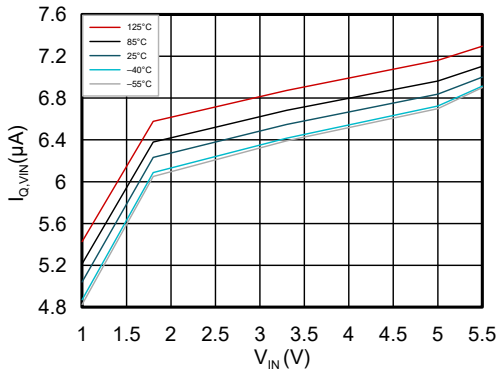
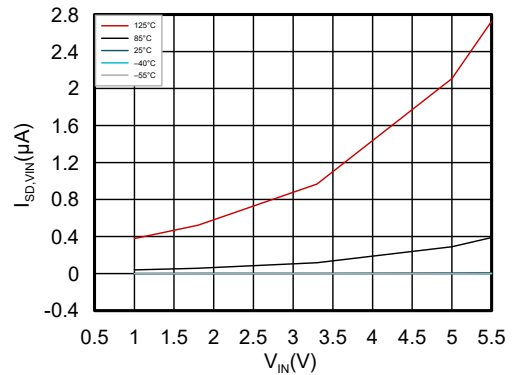
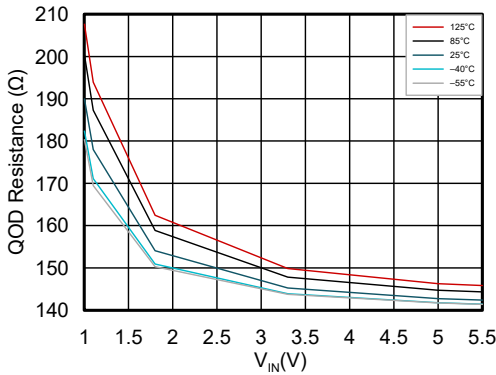


Figure 7-1.  $V_{IN}$  Quiescent Current vs Input Voltage



TPS22991B, TPS22991C

Figure 7-2.  $V_{IN}$  Shutdown Current vs Input Voltage



TPS22991B, TPS22991C

Figure 7-3. QOD Resistance vs Input Voltage

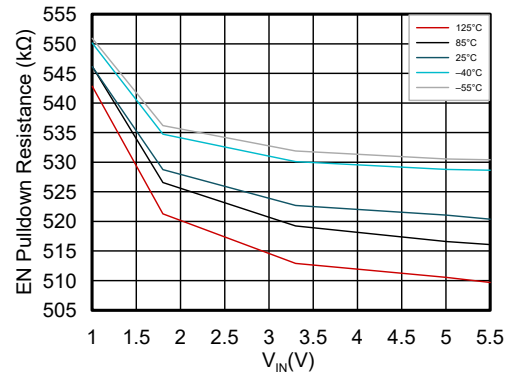


Figure 7-4. ON Pin Resistance  $R_{PD,ON}$  vs Input Voltage

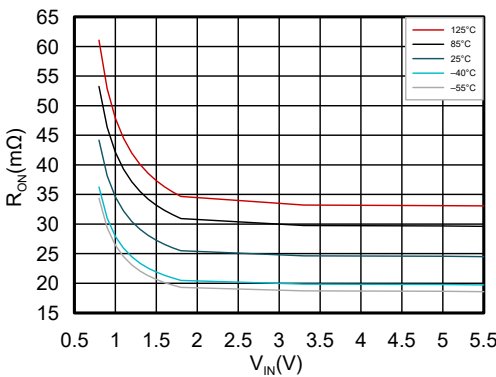
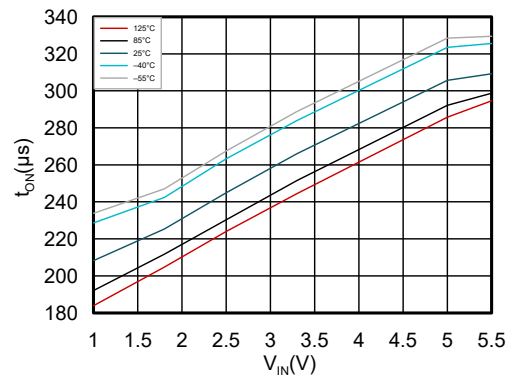


Figure 7-5.  $R_{ON}$  vs Input Voltage



$C_L = 0.1\mu F$   $R_L = 10\Omega$  TPS22991B, TPS22991BN

Figure 7-6. Turn ON Time vs Input Voltage

## 7 Typical Characteristics (continued)

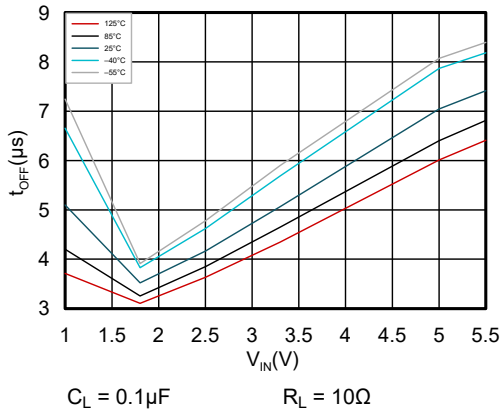


Figure 7-7. Turn OFF Time vs Input Voltage

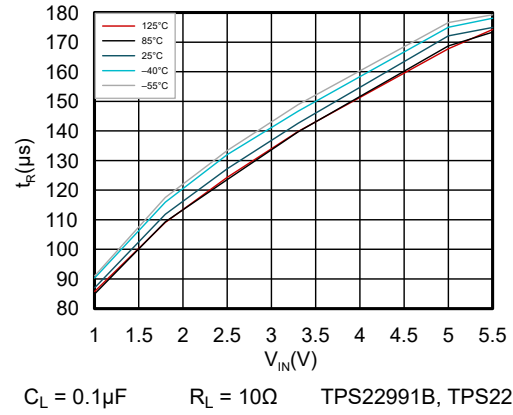


Figure 7-8. Rise Time vs Input Voltage

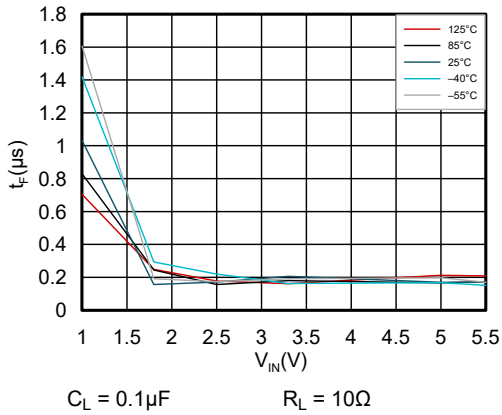


Figure 7-9. Fall Time vs Input Voltage

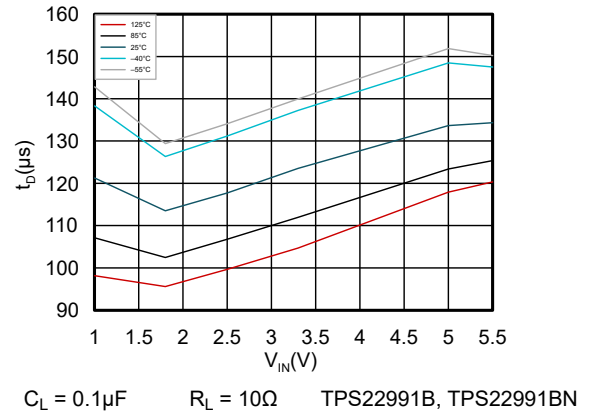


Figure 7-10. Delay Time vs Input Voltage

ADVANCE INFORMATION

## 8 Parameter Measurement Information

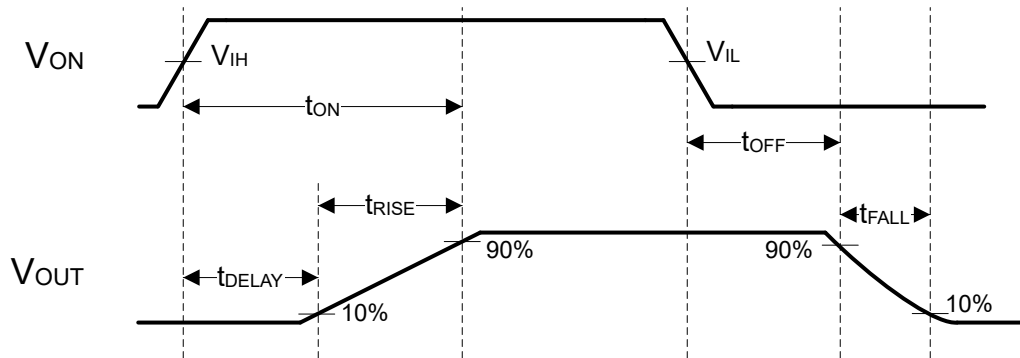


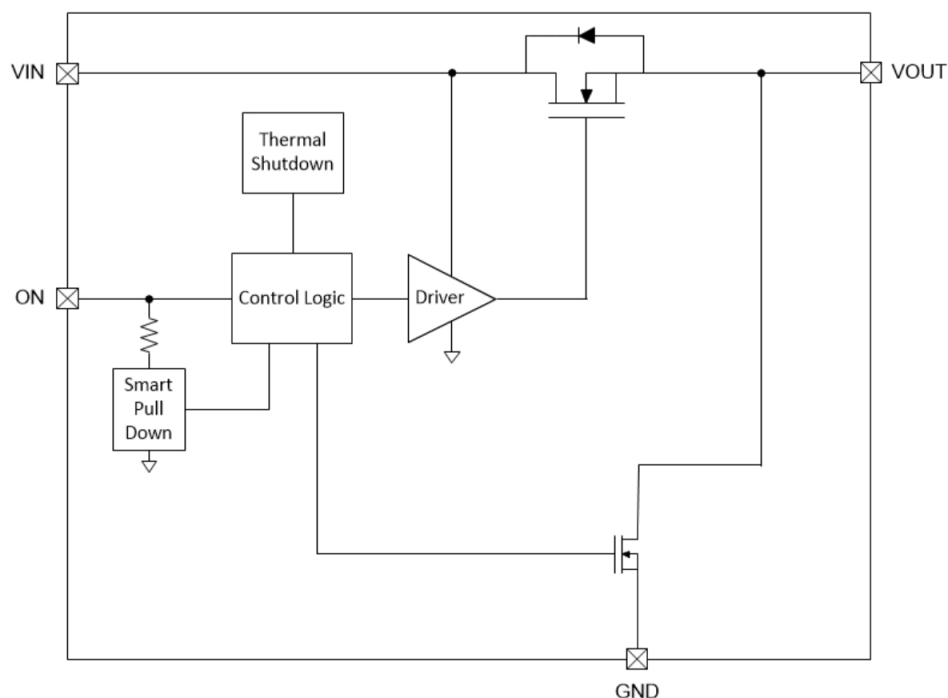
Figure 8-1. Timing Parameter Measurement Information

## 9 Detailed Description

### 9.1 Overview

The TPS22991 is a small, low  $R_{ON}$ , single channel load switch with controlled slew rate. The device contains an N-channel MOSFET that can operate over an input voltage range of 1V to 5.5V and can support a maximum continuous current of 3A. The switch is controlled by an on and off input, which is capable of interfacing directly with low-voltage control signals.

### 9.2 Functional Block Diagram



### 9.3 Feature Description

#### 9.3.1 On and Off Control

The ON pin controls the state of the switch. The ON pin is compatible with standard GPIO logic threshold so it can be used in a wide variety of applications. When power is first applied to  $V_{IN}$ , a smart pulldown is used to keep the ON pin from floating until the system sequencing is complete. After the ON pin is deliberately driven high ( $\geq V_{IH}$ ), the smart pulldown is disconnected to prevent unnecessary power loss. See [Table 9-1](#) when the ON pin smart pulldown is active.

**Table 9-1. On Pin Control**

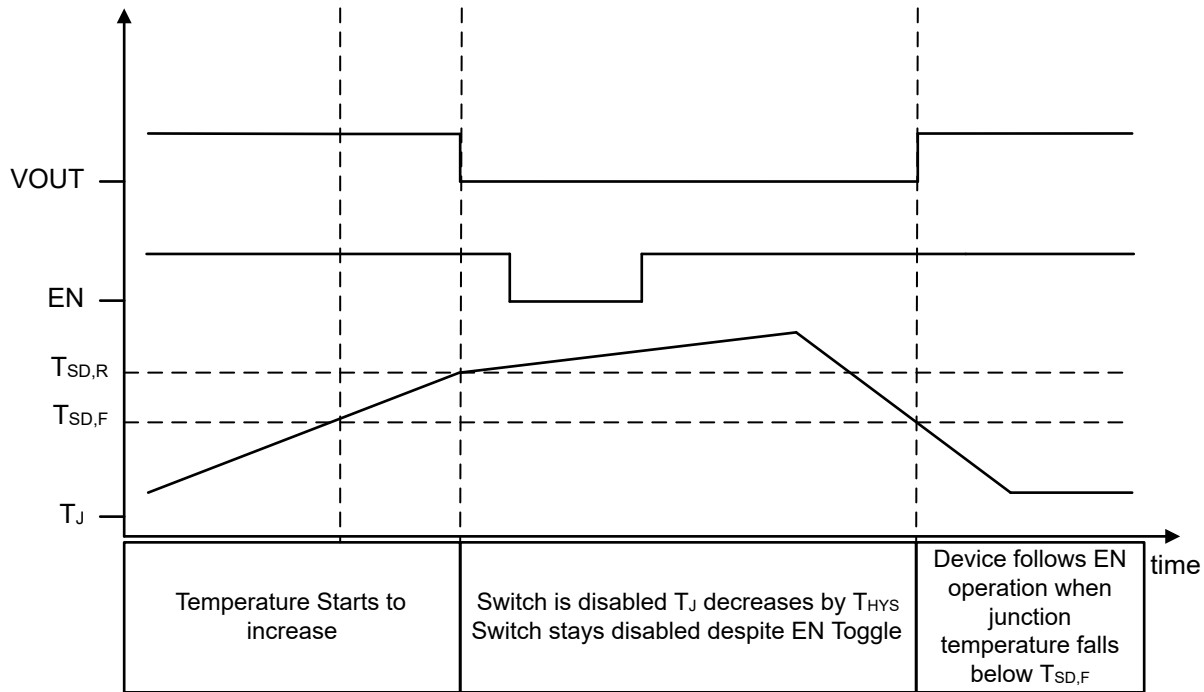
ON PIN VOLTAGE	ON PIN SMART PULLDOWN STATUS
$\leq V_{IL}$	Smart pulldown resistance active
$\geq V_{IH}$	Smart pulldown disconnected

#### 9.3.2 Quick Output Discharge

TPS22991B and TPS22991C integrates quick output discharge. When the switch is disabled, a discharge resistor is connected between VOUT and GND. This resistor has a typical value of 150 $\Omega$  when  $V_{IN} = 3.3V$ , and prevents the output from floating while the switch is disabled.

### 9.3.3 Thermal Shutdown

When the device temperature reaches  $T_{SD,R}$ , the device shuts itself off to prevent thermal damage. After the device cools off to  $T_{SD,F}$ , it turns back on. If the device is kept in a thermally stressful environment, then the device oscillates between these two states until it can keep its temperature below the thermal shutdown point.



### 9.3.4 Input Capacitor ( $C_{IN}$ )

To limit the voltage drop on the input supply caused by transient in-rush currents when the switch turns on into a discharged load capacitor or short-circuit, a capacitor needs to be placed between  $V_{IN}$  and GND. A  $1\mu\text{F}$  ceramic capacitor,  $C_{IN}$ , placed close to the pins, is usually sufficient. Higher values of  $C_{IN}$  can be used to further reduce the voltage drop during high-current application. When switching heavy loads, it is recommended to have an input capacitor about 10 times higher than the output capacitor to avoid excessive voltage drop.

### 9.3.5 Output Capacitor ( $C_L$ )

Due to the integrated body diode in the MOSFET, a  $C_{IN}$  greater than  $C_L$  is highly recommended. A  $C_L$  greater than  $C_{IN}$  can cause  $V_{OUT}$  to exceed  $V_{IN}$  when the system supply is removed. This could result in current flow through the body diode from  $V_{OUT}$  to  $V_{IN}$ . A  $C_{IN}$  to  $C_L$  ratio of 10 to 1 is recommended for minimizing  $V_{IN}$  dip caused by inrush currents during startup.

## 9.4 Device Functional Modes

The table below describes the connection of the  $V_{OUT}$  pin depending on the state of the ON pin.

ON	FAULT CONDITION	$V_{OUT}$ STATE
L	N/A	Hi-Z
H	None	$V_{IN}$ through $R_{ON}$
X	Thermal shutdown	Hi-Z

## 10 Application and Implementation

### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 10.1 Application Information

The input to output voltage drop in the device is determined by the  $R_{ON}$  of the device and the load current. The  $R_{ON}$  of the device depends upon the  $V_{IN}$  condition of the device. After the  $R_{ON}$  of the device is determined based upon the  $V_{IN}$  condition, use the below equation to calculate the input to output voltage drop.

$$\Delta V = I_{LOAD} \times R_{ON} \quad (1)$$

where

- $\Delta V$  is the voltage drop from  $V_{IN}$  to  $V_{OUT}$ .
- $I_{LOAD}$  is the load current.
- $R_{ON}$  is the on-resistance of the device for a specific  $V_{IN}$  and  $V_{BIAS}$ .

### 10.2 Typical Application

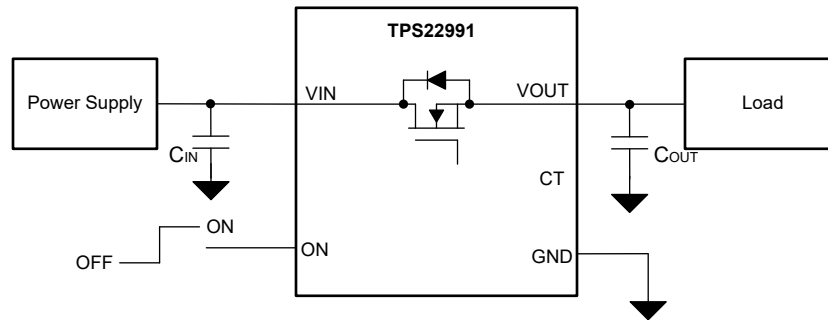


Figure 10-1. Typical Application Diagram

Table 10-1. Recommended External Components

COMPONENT	TYPICAL VALUE	PURPOSE
$C_{IN}$	1 $\mu$ F	Filtering voltage transients
$C_{OUT}$	100nF	Filtering voltage transients

#### 10.2.1 Design Requirements

For this design example, use the input parameters shown in [Table 10-2](#).

Table 10-2. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
$V_{IN}$	5V
Load current	2A
Load capacitance	10 $\mu$ F

### 10.2.2 Detailed Design Procedure

The input to output voltage drop in the device is determined by the  $R_{ON}$  of the device and the load current. The  $R_{ON}$  of the device depends upon the  $V_{IN}$  condition of the device. After the  $R_{ON}$  of the device is determined based upon the  $V_{IN}$  condition, use the below equation to calculate the input to output voltage drop.

$$\Delta V = I_{LOAD} \times R_{ON} \quad (2)$$

where

- $\Delta V$  is the voltage drop from  $V_{IN}$  to  $V_{OUT}$ .
- $I_{LOAD}$  is the load current.
- $R_{ON}$  is the on-resistance of the device for a specific  $V_{IN}$  and  $V_{BIAS}$ .

An appropriate  $I_{LOAD}$  must be chosen such that the  $I_{MAX}$  specification of the device is not violated.

To determine how much inrush current is caused by the load capacitance, use Equation 3.

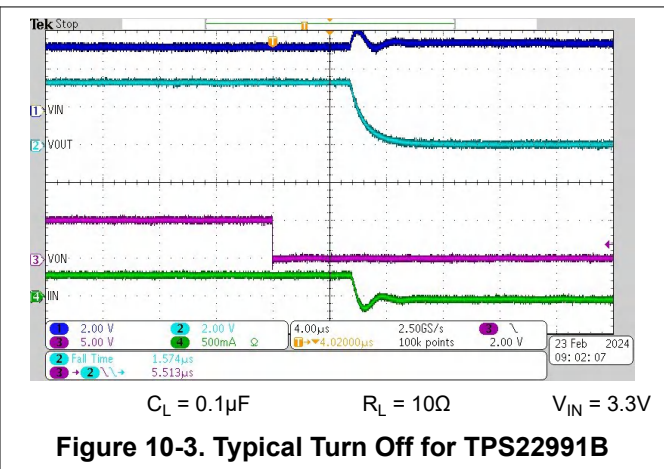
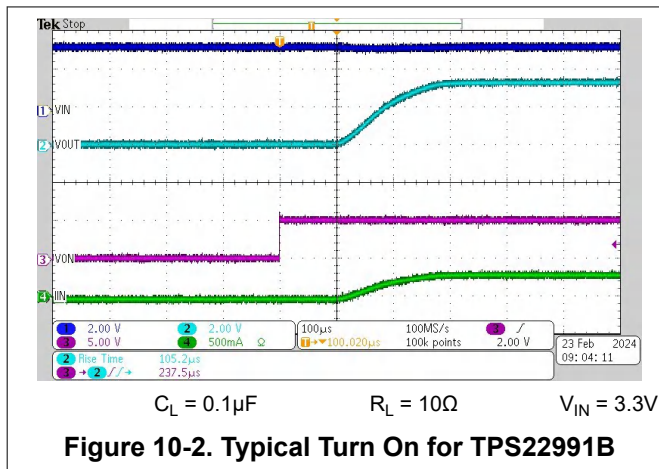
$$I_{INRUSH} = C_L \times dV_{OUT} / dt \quad (3)$$

where

- $I_{INRUSH}$  is amount of inrush current caused by  $C_L$
- $C_L$  is the load capacitance on  $V_{OUT}$
- $dt$  is the rise time for  $V_{OUT}$  when the device is enabled
- $dV_{OUT}$  is change in the  $V_{OUT}$  voltage after the device is enabled.

The slew rate of the device  $dV_{OUT}/dt$  at a given  $V_{IN}$  voltage can be found in the electrical characteristic table for a given version.  $I_{INRUSH}$  has to be within the  $I_{MAX}$  and  $I_{PLS}$  limits.

### 10.2.3 Application Curves



### 10.3 Power Supply Recommendations

The TPS22991 device is designed to operate with a  $V_{IN}$  range of 1V to 5.5V. Regulate the  $V_{IN}$  power supply well and place as close to the device terminal as possible. The power supply must be able to withstand all transient load current steps. In most situations, using an input capacitance ( $C_{IN}$ ) of  $1\mu F$  is sufficient to prevent the supply voltage from dipping when the switch is turned on. In cases where the power supply is slow to respond to a large transient current or large load current step, additional bulk capacitance can be required on the input.

## 10.4 Layout

### 10.4.1 Layout Guidelines

For best performance, all traces must be as short as possible. To be most effective, place the input and output capacitors close to the device to minimize the effects that parasitic trace inductances can have on normal operation. Using wide traces for VIN, VOUT, and GND helps minimize the parasitic electrical effects.

### 10.4.2 Layout Example

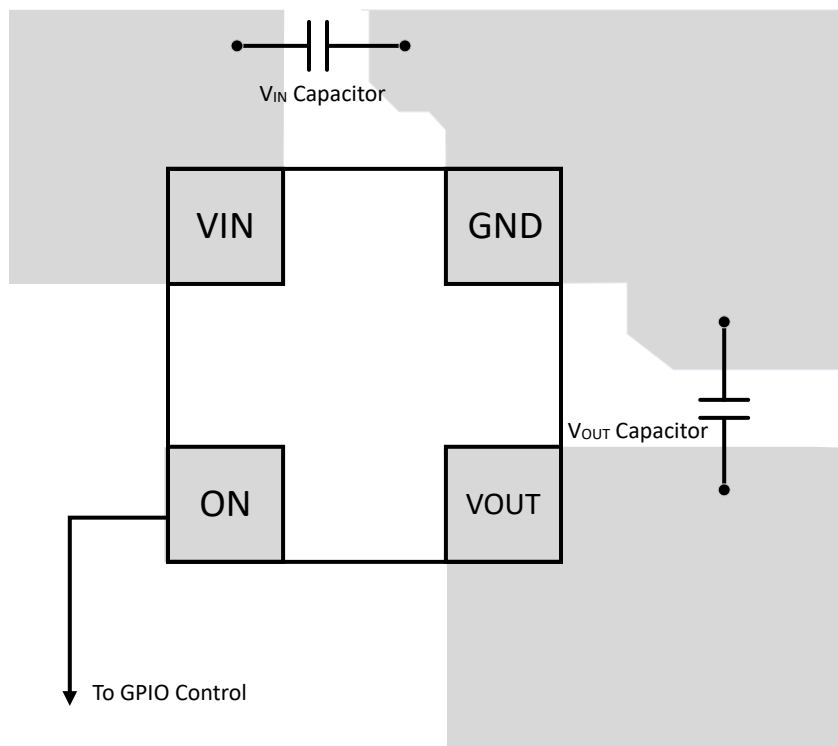


Figure 10-4. TPS22991 Layout



## 11 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

### 11.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](http://ti.com). Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 11.2 Support Resources

TI E2E™ [support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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### 11.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.  
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### 11.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 11.5 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

## 12 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

DATE	REVISION	NOTES
May 2024	*	Initial release.

## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
PTPS22991BRAAR	ACTIVE	UQFN-HR	RAA	4	3000	TBD	Call TI	Call TI	-55 to 125		Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSELETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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